Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Mounting Method:

Bracket and unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

6.2 regulator voltage

Current Rating Per Characteristic:

2.00 amperes repetitive peak forward current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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